







SN74LV14A

SCLS386L - SEPTEMBER 1997 - REVISED DECEMBER 2022

SN74LV14A Hex Schmitt-Trigger Inverters

1 Features

Texas

- V_{CC} operation of 2 V to 5.5 V
- Max t_{pd} of 10 ns at 5 V

Instruments

- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 > 2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- Support Mixed-Mode Voltage Operation on All Ports
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA
 Per JESD 17

2 Applications

- Network Switches
- Wearable Health and Fitness Devices
- PDAs
- LCD TVs
- Power Infrastructure

3 Description

These hex Schmitt-trigger inverters are designed for 2 V to 5.5 V V_{CC} operation.

The SN74LV14A devices contain six independent inverters. These devices perform the Boolean function $Y = \overline{A}$.

Package Information

PART NUMBER	PACKAGE (1)	BODY SIZE (NOM)							
	TVSOP (14)	3.60 mm × 4.40 mm							
SN74LV14A	SOIC (14)	8.65 mm × 3.91 mm							
SIN74LV 14A	SSOP (14)	6.20 mm × 5.30 mm							
	TSSOP (14)	5.00 mm × 4.40 mm							

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Figure 3-1. Simplified Schematic





Table of Contents

1 Features	.1
2 Applications	1
3 Description	.1
4 Revision History	2
5 Pin Configuration and Functions	.3
Pin Functions	3
6 Specifications	4
6.1 Absolute Maximum Ratings	4
6.2 ESD Ratings	
6.3 Recommended Operating Conditions	4
6.4 Thermal Information	5
6.5 Electrical Characteristics	.5
6.6 Switching Characteristics, V _{CC} = 2.5 V ± 0.2 V	.6
6.7 Switching Characteristics, V _{CC} = 3.3 V ± 0.3 V	.6
6.8 Switching Characteristics, V _{CC} = 5 V ± 0.5 V	.6
6.9 Noise Characteristics	6
6.10 Operating Characteristics	6
6.11 Typical Characteristics	7
7 Parameter Measurement Information	8
8 Detailed Description	9

8.1 Overview	9
8.2 Functional Block Diagram	
8.3 Feature Description.	9
8.4 Device Functional Modes	
9 Application and Implementation	. 10
9.1 Application Information	
9.2 Typical Application	
10 Power Supply Recommendations	.12
11 Layout	
11.1 Layout Guidelines	12
11.2 Layout Example	12
12 Device and Documentation Support	.13
12.1 Related Links	. 13
12.2 Receiving Notification of Documentation Updates.	.13
12.3 Support Resources	13
12.4 Trademarks	.13
12.5 Electrostatic Discharge Caution	.13
12.6 Glossary	
13 Mechanical, Packaging, and Orderable	
Information	.13

4 Revision History

Changes from Revision K (September 2014) to Revision L (December 2022)	Page
Updated the format for tables, figures, and cross-references throughout the document	1
Changes from Revision J (September 1997) to Revision K (September 2014)	Page
Updated document to new TI data sheet format	1
Removed Ordering Information table	1
Added Applications	1
Added Device Information table	1
Added Pin Functions table	3
Changed MAX operating temperature to 125°C in Recommended Operating Conditions table	4
Added Thermal Information table	
Added Typical Characteristics	7
Added Application and Implementation section	10
Added Power Supply Recommendations and Layout sections	



5 Pin Configuration and Functions



Figure 5-1. SN74LV14A D, DB, DGV, NS OR PW Package Top View



Figure 5-2. SN74LV14A RGY Package Top View

Pin Functions

	PIN			
	SN74LV	14A	TYPE ⁽¹⁾	DESCRIPTION
NAME	D, DB, DGV, NS, PW	RGY		
1A	1	1	I	Input 1A
1Y	2	2	0	Output 1Y
2A	3	3	I	Input 2A
2Y	4	4	0	Output 2Y
3A	5	5	I	Input 3A
3Y	6	6	0	Output 3Y
4Y	8	8	0	Output 4Y
4A	9	9	I	Input 4A
5Y	10	10	0	Output 5Y
5A	11	11	I	Input 5A
6Y	12	12	0	Output 6Y
6A	13	13	I	Input 6A
GND	7	7	—	Ground Pin
NC	_		-	No Connection
V _{CC}	14	14	_	Power Pin

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

6 Specifications 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the high	-0.5	7	V	
Vo	Output voltage range ^{(2) (3)}		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{ок}	Output clamp current	V _O < 0		-50	mA
Ι _Ο	Continuous output current	$V_{O} = 0$ to V_{CC}		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature range	-65	150	°C	

(1) Stresses beyond those listed under Section 6.1 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Section 6.3 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 5.5-V maximum.

6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all $pins^{(2)}$	±1000	v
		Machine Model	±200	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			SN74LV14	A	UNIT
			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 2 V		-50	μA
	Ligh lovel output ourrent	V _{CC} = 2.3 V to 2.7 V		-2	
I _{OH}	High-level output current	V _{CC} = 3 V to 3.6 V		-6	mA
		V _{CC} = 4.5 V to 5.5 V		-12	
		V _{CC} = 2 V		50	μA
		V _{CC} = 2.3 V to 2.7 V		2	
IOL	Low-level output current	V _{CC} = 3 V to 3.6 V		6	mA
		V _{CC} = 4.5 V to 5.5 V		12	
T _A	Operating free-air temperature	· · · · ·	-40	125	°C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).



6.4 Thermal Information

				SN74	_V14A			
	THERMAL METRIC ⁽¹⁾	D	RGY	UNIT				
				14 F	PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	94.9	107.4	130.4	91.4	122.6	57.6	
R _θ JC(top)	Junction-to-case (top) thermal resistance	56.3	59.9	53.4	49.0	51.3	70.4	
$R_{\theta JB}$	Junction-to-board thermal resistance	49.2	54.7	63.5	50.2	64.4	33.6	°c/w
Ψ _{JT}	Junction-to-top characterization parameter	20.7	21.0	7.3	15.3	6.8	3.5	
Ψ _{JB}	Junction-to-board characterization parameter	48.9	51.2	62.8	49.8	63.8	33.7	
R _θ JC(bot)	Junction-to-case (bottom) thermal resistance	-	-	-	-	-	14.1	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{cc}		74LV14A °C to 85°C	;	SN 40°	UNIT		
				MIN	TYP	MAX	MIN	TYP	MAX	
			2.5 V			1.75			1.75	
V _{T+}	Positive-going threshold		3.3 V			2.31			2.31	V
			5 V			3.5			3.5	
			2.5 V	0.75			0.75			
V _{T-}	Negative-going threshold		3.3 V	0.99			0.99			V
			5 V	1.5			1.5			
			2.5 V	0.25			0.25			
$\Delta V_T \left(V_{T+} - V_{T-} \right)$	Hysteresis		3.3 V	0.33			0.33			V
			5 V	0.5			0.5			
	High-level output voltage	I _{OH} = –50 μA	2 V to 5.5 V	V _{CC} - 0.1			V _{CC} - 0.1			
V _{OH}		I _{OH} = -2 mA	2.3 V	2			2			v
		I _{OH} =6 mA	3 V	2.48			2.48			
		I _{OH} = -12 mA	4.5 V	3.8			3.8			
		I _{OL} = 50 μA	2 V to 5.5 V			0.1			0.1	
V _{OL}	Low-level output voltage	I _{OL} = 2 mA	2.3 V			0.4			0.4	V
01		I _{OL} = 6 mA	3 V			0.44			0.44	
		I _{OL} = 12 mA	4.5 V			0.55			0.55	
I _I	Input leakage current	V _I = V _{CC} or GND	0 to 5.5 V			±1			±1	μA
I _{CC}	Static supply current	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	5.5 V			20			20	μA
I _{off}	Input/Output Power-Off Leakage Current	$V_1 \text{ or } V_0 = 0 \text{ to } 5.5 \text{ V}$	0			5			5	μA
0	Innut conseitance		3.3 V		2.3			2.3		~ F
Ci	Input capacitance	$V_{I} = V_{CC} \text{ or } GND$	5 V		2.3			2.3		pF

6.6 Switching Characteristics, V_{CC} = 2.5 V \pm 0.2 V

PARAMETER	FROM (INPUT)		TO (OUTPUT)	LOAD CAPACITANCE		T _A = 25°C		SN74L –40°C te		SN74L -40°C to		UNIT
			TFOT) CAFACITANCE		TYP	MAX	MIN	MAX	MIN	MAX		
t _{pd} A	A Y		C _L = 15 pF		10.2 ⁽¹⁾	19.7 <mark>(1)</mark>	1	22	1	23	ns	
		AY	C _L = 50 pF		13.3	24	1	27	1	28	115	

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.7 Switching Characteristics, V_{CC} = 3.3 V ± 0.3 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		٦	T _A = 25°C		SN74L –40°C to		SN74LV1 –40°C to 1		UNIT
			(TFUT) CAFACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
•	۸	V	C _L = 15 pF		7.3 ⁽¹⁾	12.8 <mark>(1)</mark>	1	15	1	16	P 0
Чрd	A	l t	C _L = 50 pF		9.6	16.3	1	18.5	1	19.5	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.8 Switching Characteristics, V_{CC} = 5 V ± 0.5 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			SN74L –40°C te		SN74LV [/] –40°C to 1	UNIT	
			CALACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
+	^	X	C _L = 15 pF		5.1 ⁽¹⁾	8.6 <mark>(1)</mark>	1	10	1	11	n 0
^L pd	A	T T	C _L = 50 pF		6.7	10.6	1	12	1	13	ns

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.9 Noise Characteristics

V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C⁽¹⁾

		SN7	4LV14A		UNIT
		MIN	TYP	MAX	
V _{OL(P)}	Quiet output, maximum dynamic		0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic		-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic		3.1		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

(1) Characteristics are for surface-mount packages only.

6.10 Operating Characteristics

T_A = 25°C

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
C	Power dissipation capacitance	C ₁ = 50 pF f = 10 MHz	3.3 V	8.8	۶
Cpd		$C_{L} = 50 \text{ pr}$ $T = 10 \text{ MHz}$	5 V	9.6	рг



6.11 Typical Characteristics



7 Parameter Measurement Information





- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z₀ = 50 Ω , t_r \leq 3 ns,
- t_f ≤ 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- $\mathsf{E}. \quad t_{\mathsf{PLZ}} \text{ and } t_{\mathsf{PHZ}} \text{ are the same as } t_{\mathsf{dis}}.$
- $\label{eq:F.transform} F. \quad t_{\text{PZL}} \text{ and } t_{\text{PZH}} \text{ are the same as } t_{\text{en}}.$
- $G. \quad t_{PHL} \text{ and } t_{PLH} \text{ are the same as } t_{pd}.$
- H. All parameters and waveforms are not applicable to all devices.

Figure 7-1. Load Circuit and Voltage Waveforms



8 Detailed Description

8.1 Overview

These hex Schmitt-trigger inverters are designed for 2 V to 5.5 V V_{CC} operation.

The SN74LV14A devices contain six independent inverters. These devices perform the Boolean function $Y = \overline{A}$.

These devices are fully specified for partial-power-down application using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

8.2 Functional Block Diagram



Figure 8-1. Logic Diagram, Each Inverter (Positive Logic)

8.3 Feature Description

- Wide operating voltage range
 - Operates From 2 V to 5.5 V
- Allows up or down voltage translation
 - Inputs and outputs accept voltages to 5.5 V
- I_{off} feature
 - Allows voltages on the inputs and outputs when V_{CC} is 0 V
- Schmitt-trigger inputs allow for slow or noisy inputs

8.4 Device Functional Modes

Table 8-1. Function Table (Each Inverter)

INPUT ⁽¹⁾ A	OUTPUT ⁽²⁾ Y
Н	L
L	Н

- H = High Voltage Level, L = Low Voltage Level, X = Don't Care
- (2) H = Driving High, L = Driving Low, Z = High Impedance State



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

Schmitt triggers should be used anytime you need to translate a sign wave into a square wave as shown in Figure 9-1. They may also be used where a slow or noisy input needs to be sped up or cleaned up as shown in Figure 9-2.

9.2 Typical Application









9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For rise time and fall time specifications, see $\Delta t/\Delta V$ in Section 6.3 table.
 - For specified high and low levels, see V_{IH} and V_{IL} in Section 6.3 table.
 - Inputs and outputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend Output Conditions:
 - Load currents should not exceed 35 mA per output and 50 mA total for the part.

9.2.3 Application Curves

Schmitt triggers should be used any time you need to 1. Change a sign wave into a square wave.



2. Have noisy signals that need to be cleaned up



3. Have slow edges that need to be converted to fast edges.



Figure 9-3. Schmitt Trigger Curves



10 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Section 6.3 table.

Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1 μ F capacitor is recommended. If there are multiple V_{CC} terminals then 0.01 μ F or 0.022 μ F capacitors are recommended for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1 μ F and 1.0 μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for the best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in the Figure 11-1 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver.

11.2 Layout Example



Figure 11-1. Layout Diagram



12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	PRODUCT FOLDER SAMPLE & BUY		TOOLS & SOFTWARE	SUPPORT & COMMUNITY					
SN54LV14A	Click here	Click here	Click here	Click here	Click here					
SN74LV14A	Click here	Click here	Click here	Click here	Click here					

Table 12-1. Related Links

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV14AD	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125	LV14A	
SN74LV14ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples
SN74LV14ADGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples
SN74LV14ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples
SN74LV14ADRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples
SN74LV14ANSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV14A	Samples
SN74LV14APW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125	LV14A	
SN74LV14APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples
SN74LV14APWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples
SN74LV14APWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples
SN74LV14ARGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV14A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



www.ti.com

PACKAGE OPTION ADDENDUM

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LV14A :

- Automotive : SN74LV14A-Q1
- Enhanced Product : SN74LV14A-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

www.ti.com

Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV14ADBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74LV14ADGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74LV14ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV14ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV14ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV14ADRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LV14ANSR	SOP	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74LV14ANSR	SOP	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74LV14APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV14APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV14APWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV14APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV14APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV14ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



www.ti.com

PACKAGE MATERIALS INFORMATION

7-Dec-2024



*All dimensions are nominal Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV14ADBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74LV14ADGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74LV14ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV14ADR	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV14ADRG4	SOIC	D	14	2500	340.5	336.1	32.0
SN74LV14ADRG4	SOIC	D	14	2500	356.0	356.0	35.0
SN74LV14ANSR	SOP	NS	14	2000	367.0	367.0	38.0
SN74LV14ANSR	SOP	NS	14	2000	356.0	356.0	35.0
SN74LV14APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV14APWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV14APWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74LV14APWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV14APWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV14ARGYR	VQFN	RGY	14	3000	360.0	360.0	36.0

D0014A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



D0014A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0014A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DB0014A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not

- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-150.



DB0014A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0014A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



PW0014A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0014A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0014A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

RGY 14

3.5 x 3.5, 0.5 mm pitch

GENERIC PACKAGE VIEW

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





RGY0014A



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
 The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



RGY0014A

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



RGY0014A

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated